

CMP401/CMP402—SPECIFICATIONS

ELECTRICAL SPECIFICATIONS (@ $V_{+ANA} = V_{+DIG} = 5.0\text{ V}$, $V_{CM} = 0.1\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage ¹	V_{OS}	$T_A = 25^{\circ}\text{C}$			3	mV
	V_{OS}				4	mV
Hysteresis				2		mV
Input Bias Current	I_B	$T_A = 25^{\circ}\text{C}$			3	μA
	I_B				4	μA
Input Offset Current	I_{OS}				± 3	μA
Input Common-Mode Voltage Range	V_{CM}		0		4.0	V
Common-Mode Rejection	CMRR	$0.1\text{ V} \leq V_{CM} \leq 3.9\text{ V}$	60			dB
Large-Signal Voltage Gain	A_{VO}	$R_L = 10\text{ k}\Omega$		10		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			1		$\mu\text{V}/^{\circ}\text{C}$
OUTPUT CHARACTERISTICS						
Output High Voltage	V_{OH}	$I_{OH} = -3.2\text{ mA}$	4.6			V
Output Low Voltage	V_{OL}	$I_{OL} = 3.2\text{ mA}$			0.2	V
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_{+ANA} and V_{+DIG} 2.7 V to 6 V	60			dB
Analog Supply Current – CMP401	I_{ANA}	$T_A = 25^{\circ}\text{C}$			6.5	mA
Digital Supply Current – CMP401	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$, $T_A = 25^{\circ}\text{C}$			2.0	mA
Analog Supply Current – CMP401	I_{ANA}				8.0	mA
Digital Supply Current – CMP401	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$			2.25	mA
Analog Supply Current – CMP402	I_{ANA}	$T_A = 25^{\circ}\text{C}$			1.4	mA
Digital Supply Current – CMP402	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$, $T_A = 25^{\circ}\text{C}$			2.0	mA
Analog Supply Current – CMP402	I_{ANA}				1.75	mA
Digital Supply Current – CMP402	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$			2.25	mA
DYNAMIC PERFORMANCE						
Propagation Delay – CMP401	t_p	100 mV Step with 20 mV OD $T_A = 25^{\circ}\text{C}$		17	23	ns
	t_p	100 mV Step with 5 mV OD $T_A = 25^{\circ}\text{C}$		33		ns
	t_p	100 mV Step with 20 mV OD $T_A = 25^{\circ}\text{C}$			30	ns
Propagation Delay – CMP402	t_p	100 mV Step with 20 mV OD $T_A = 25^{\circ}\text{C}$		54	65	ns
	t_p	100 mV Step with 5 mV OD $T_A = 25^{\circ}\text{C}$		60		ns
	t_p	100 mV Step with 20 mV OD			75	ns

ELECTRICAL SPECIFICATIONS (@ $V_{ANA} = V_{DIG} = 3.0\text{ V}$, $V_{CM} = 0.1\text{ V}$, $T_A = 25^{\circ}\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage ¹	V_{OS}				4.5	mV
Input Common-Mode Voltage Range	V_{CM}		0		2.0	V
Input Differential Voltage Range	V_{DIFF}		± 2.0			V
Common-Mode Rejection	CMRR	$0.1\text{ V} \leq V_{CM} \leq 1.9\text{ V}$	60			dB
OUTPUT CHARACTERISTICS						
Output High Voltage	V_{OH}	$I_{OH} = -3.2\text{ mA}$	2.6			V
Output Low Voltage	V_{OL}	$I_{OL} = 3.2\text{ mA}$			0.25	V
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_{+ANA} and V_{+DIG} 2.7 V to 6 V	60			dB
Analog Supply Current – CMP401	I_{ANA}				6	mA
Digital Supply Current – CMP401	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$			1	mA
Analog Supply Current – CMP402	I_{ANA}				1.2	mA
Digital Supply Current – CMP402	I_{DIG}	$V_O = 0\text{ V}$, $R_L = \infty$			1	mA
DYNAMIC PERFORMANCE						
Propagation Delay – CMP401	t_p	100 mV Step with 20 mV OD		32		ns
Propagation Delay – CMP402	t_p	100 mV Step with 20 mV OD		70		ns

ELECTRICAL SPECIFICATIONS (@ $V_{\pm\text{ANA}} = \pm 5\text{ V}$, $V_{\text{DIG}} = 5.0\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage ¹	V_{OS}	$V_{\text{CM}} = 0\text{ V}$			3	mV
Input Common-Mode Voltage Range	V_{CM}		-5.0		+4.0	V
Input Differential Voltage Range	V_{DIFF}		± 8.0			V
Common-Mode Rejection	CMRR	$-4.9\text{ V} \leq V_{\text{CM}} \leq 3.9\text{ V}$	60			dB
Offset Voltage Drift	$\Delta V_{\text{OS}}/\Delta T$			1	5	$\mu\text{V}/^\circ\text{C}$
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{\pm\text{ANA}} \pm 3\text{ V}$ to $\pm 6\text{ V}$	60			dB
Analog Supply Current – CMP401	I_{ANA}				6.5	mA
Digital Supply Current – CMP401	I_{DIG}	$V_{\text{O}} = 0\text{ V}$, $R_{\text{L}} = \infty$			2.0	mA
Analog Supply Current – CMP402	I_{ANA}				2.0	mA
Digital Supply Current – CMP402	I_{DIG}	$V_{\text{O}} = 0\text{ V}$, $R_{\text{L}} = \infty$			2.0	mA
DYNAMIC PERFORMANCE						
Propagation Delay – CMP401	t_{p}	100 mV Step with 20 mV OD			23	ns
Propagation Delay – CMP402	t_{p}	100 mV Step with 20 mV OD			65	ns

NOTES¹Offset voltage is defined as $(V_{\text{OS}+} + V_{\text{OS}-})/2$.

Specifications subject to change without notice.

CMP401/CMP402

ABSOLUTE MAXIMUM RATINGS¹

Total Analog Supply Voltage 16 V
Digital Supply Voltage 7 V
Analog Positive Supply—Digital Positive Supply -200 mV
Input Voltage² ±7 V
Differential Input Voltage ±9 V
Output Short-Circuit Duration to GND Indefinite
Storage Temperature Range
S, RU Package -65°C to +150°C
Operating Temperature Range
CMP401G, CMP402G -40°C to +125°C
Junction Temperature Range
S, RU Package -65°C to +150°C
Lead Temperature Range (Soldering 60 sec) 300°C

Package Type	θ_{JA} ³	θ_{JC}	Units
16-Lead SOIC (S)	113	37	°C/W
16-Lead TSSOP (RU)	180	37	°C/W

NOTES
¹Absolute Maximum Ratings apply to packaged parts, unless otherwise noted.
²The analog input voltage is equal to ±7 V or the analog supply voltage, whichever is less.
³ θ_{JA} is specified for the worst-case conditions, i.e., θ_{JA} is specified for device soldered in circuit board for SOIC and TSSOP packages.

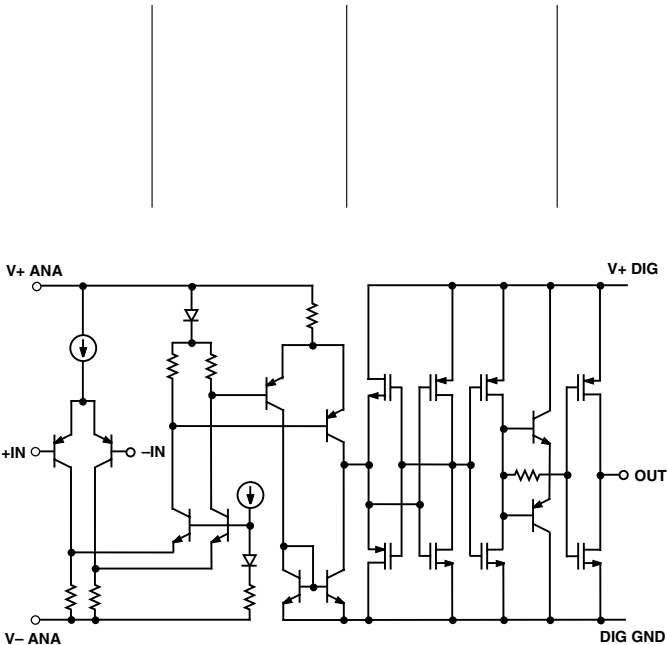
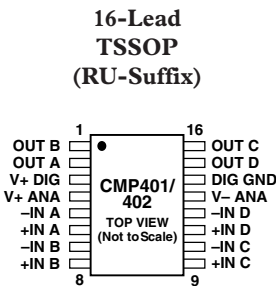
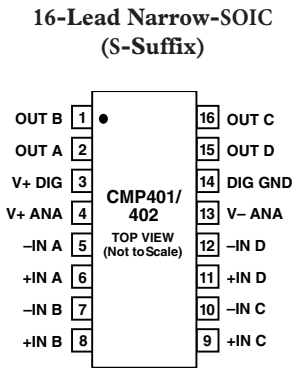


Figure 1. Simplified Schematic

PIN CONFIGURATIONS



CAUTION

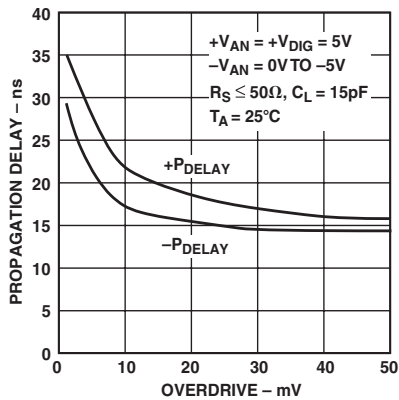
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the CMP401/CMP402 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



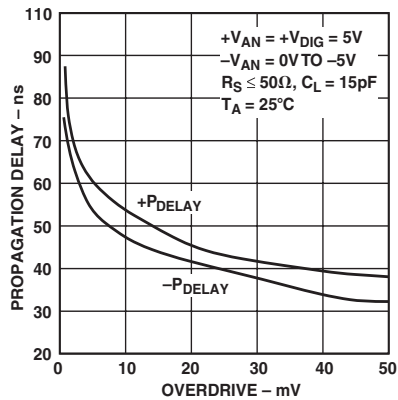
Revision History

Location	Page	Location	Page
Data Sheet changed from REV. A to REV. B.		Data Sheet changed from REV. 0 to REV. A.	
Changed SO-16 to 16-Lead SOIC	Throughout	Edits to GENERAL DESCRIPTION	1
Moved Revision History	4	Edits to ABSOLUTLE MAXIMUM RATINGS.	4
Moved Outline Dimensions	8	Edits to PACKAGE TYPE.	4
Updated Outline Dimensions	8	Edits to ORDERING GUIDE	4
Changes to Ordering Guide	8	Deleted DICE CHARACTERISTICS	4
		Edits to CMP401/CMP402 PIN CONFIRGURATIONS. . .	4

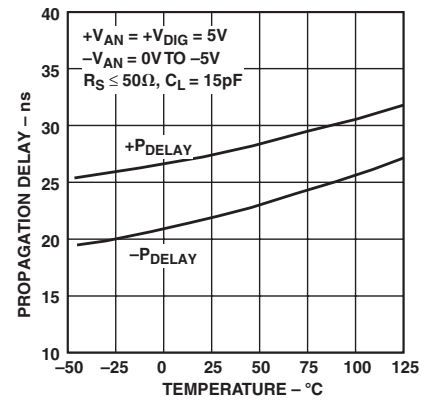
Typical Performance Characteristics—CMP401/CMP402



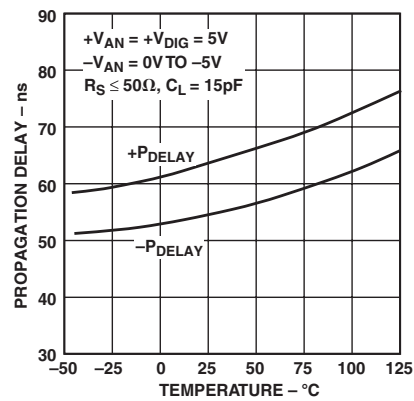
TPC 1. CMP401 Propagation Delay vs. Overdrive



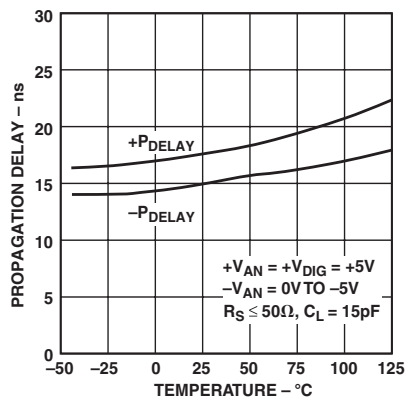
TPC 2. CMP402 Propagation Delay vs. Overdrive



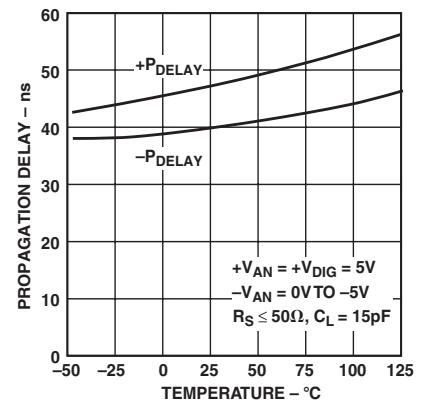
TPC 3. CMP401 Propagation Delay vs. Temperature - 5 mV OD



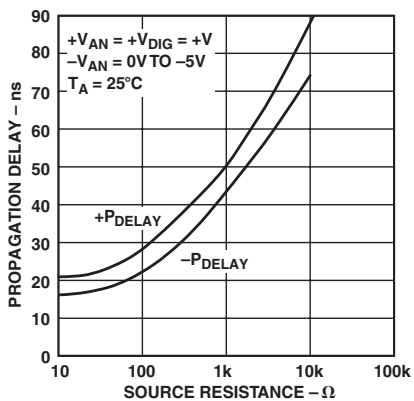
TPC 4. CMP402 Propagation Delay vs. Temperature - 5 mV OD



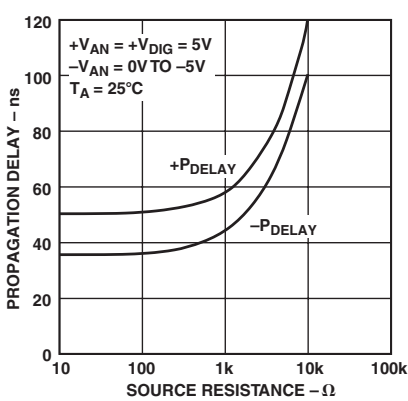
TPC 5. CMP401 Propagation Delay vs. Temperature - 20 mV OD



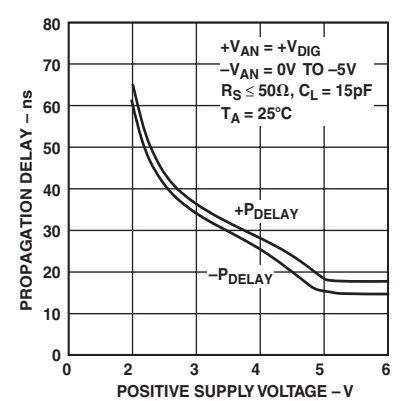
TPC 6. CMP402 Propagation Delay vs. Temperature - 20 mV OD



TPC 7. CMP401 Propagation Delay vs. Source Resistance - 20 mV OD

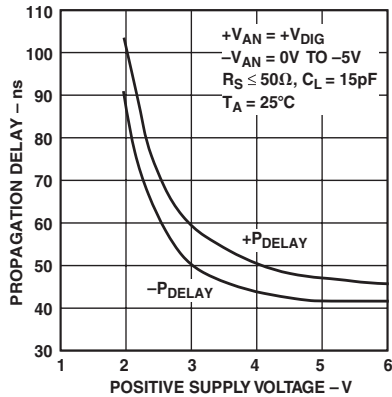


TPC 8. CMP402 Propagation Delay vs. Source Resistance - 20 mV OD

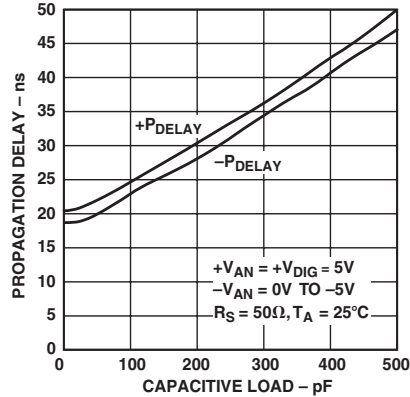


TPC 9. CMP401 Propagation Delay vs. Supply Voltage - 20 mV OD

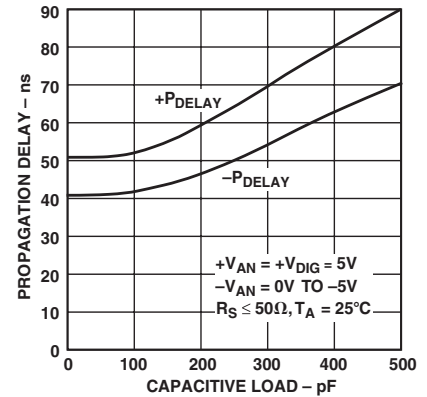
CMP401/CMP402



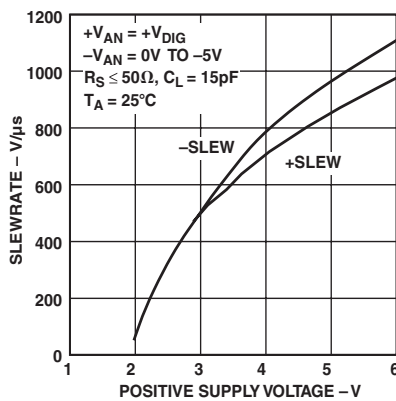
TPC 10. CMP402 Propagation Delay vs. Supply Voltage – 20 mV OD



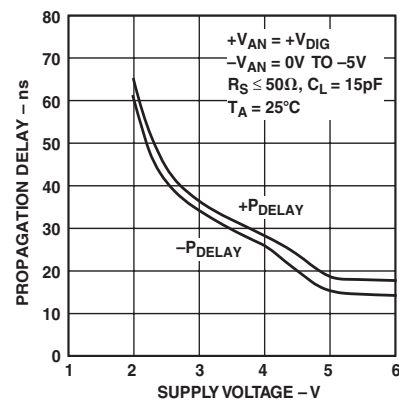
TPC 11. CMP401 Propagation Delay vs. Capacitive Load



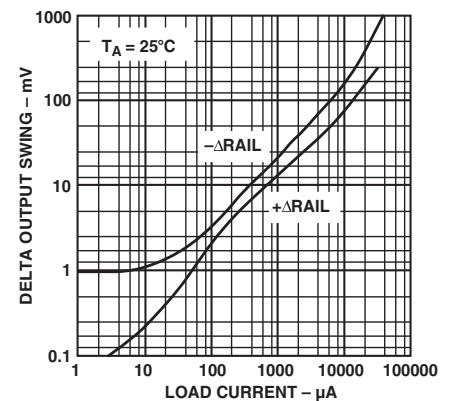
TPC 12. CMP402 Propagation Delay vs. Capacitive Load



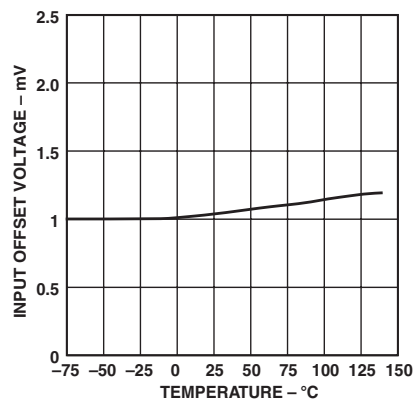
TPC 13. CMP401/CMP402 Slew Rate vs. Positive Supply Voltage



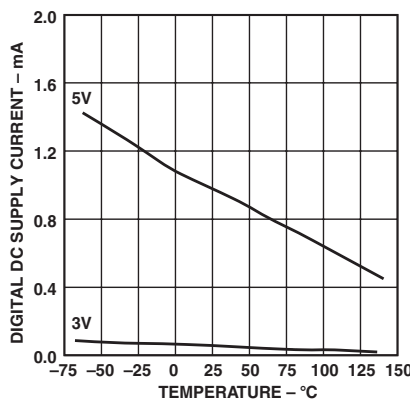
TPC 14. CMP401 Propagation Delay vs. Supply Voltage



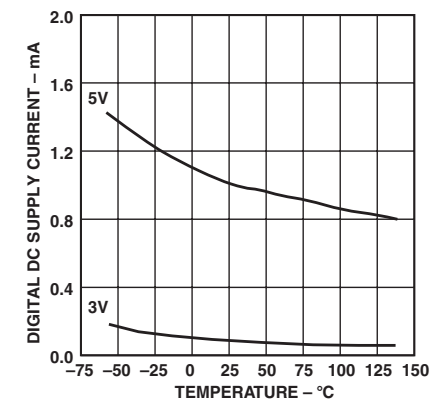
TPC 15. CMP401/CMP402 Delta Output Swing from Power Supplies vs. Load Current



TPC 16. CMP401/CMP402 Input Offset Voltage vs. Temperature

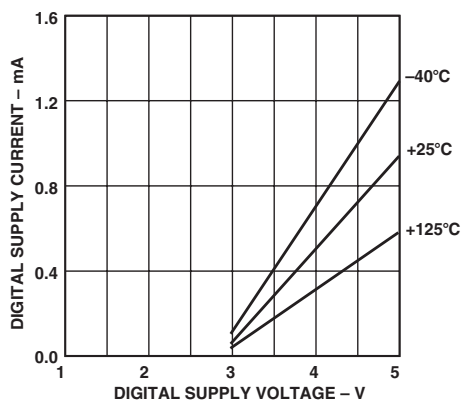


TPC 17. CMP401 Digital Supply Current vs. Temperature

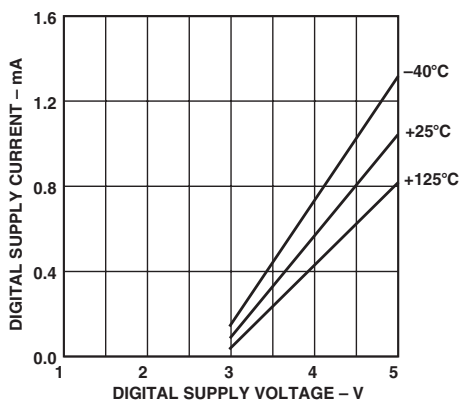


TPC 18. CMP402 Digital Supply Current vs. Temperature

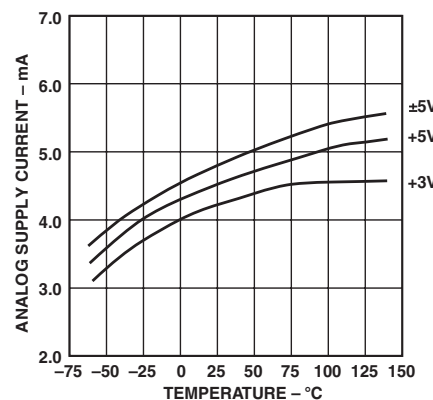
Typical Performance Characteristics—CMP401/CMP402



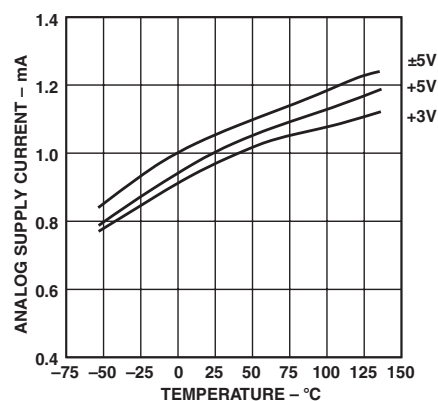
TPC 19. CMP401 Digital Supply Current vs. Digital Supply Voltage



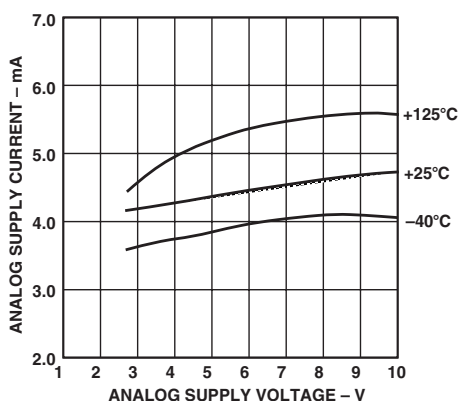
TPC 20. CMP402 Digital Supply Current vs. Digital Supply Voltage



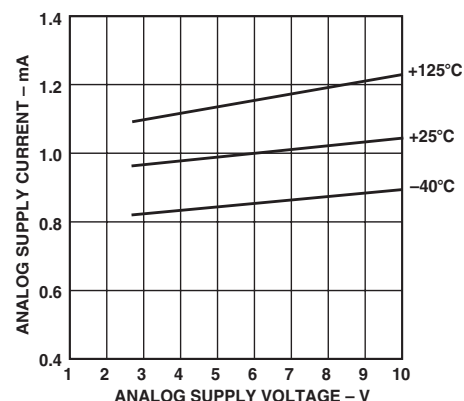
TPC 21. CMP401 Analog Supply Current vs. Temperature



TPC 22. CMP402 Analog Supply Current vs. Temperature

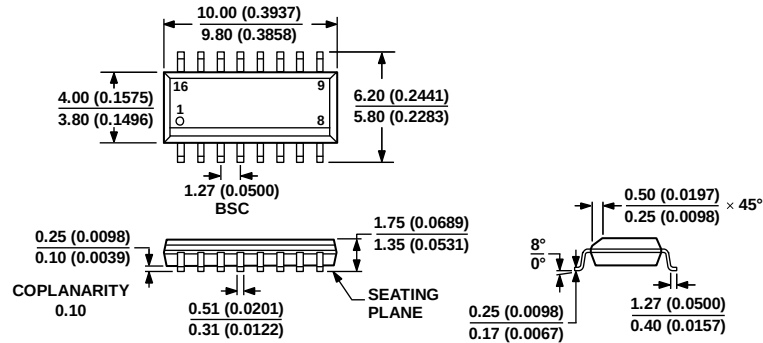


TPC 23. CMP401 Analog Supply Current vs. Analog Supply Voltage



TPC 24. CMP402 Analog Supply Current vs. Analog Supply Voltage

OUTLINE DIMENSIONS

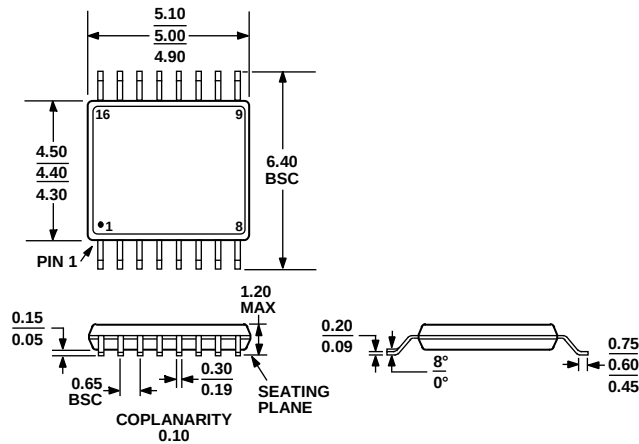


COMPLIANT TO JEDEC STANDARDS MS-012-AC
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 1. 16-Lead Standard Small Outline Package [SOIC_N]

Narrow Body
(R-16)
S-Suffix

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 2. 16-Lead Thin Shrink Small Outline Package [TSSOP]

(RU-16)

Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
CMP401GRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
CMP401GSZ	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP401GSZ-REEL	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP402GRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
CMP402GSZ	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16
CMP402GSZ-REEL	−40°C to +125°C	16-Lead Standard Small Outline Package [SOIC_N]	R-16

¹ Z = RoHS Compliant Part.